NSN 5961-01-186-9693

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Inclosure Material: Metal **Overall Length:** 1.573 inches **Overall Height:** 0.328 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 collector to base voltage/static/emitter open and -7.0 emitter to base voltage, static, collector open and -100.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** -20.00 amperes source cutoff current and -0.50 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 80.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin and 1 case

Shelf Life:

NI/o

Specification Data:

81349-mil-s-19500/505 government specification

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Demilitarization:

No

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